



**TET ESTEL AS**  
ESTONIA

**May**  
**2013**

**Series**  
**TL271-320**

**Avalanche Stud Mounted Thyristor**  
**Type TL271-320**

Center amplifying gate

Guaranteed avalanche power dissipation in reverse direction

Designed for traction and industrial applications

Maximum mean on-state current	$I_{TAV}$	<b>320 A</b>
Maximum repetitive peak off-state and reverse voltage	$U_{DRM}$ $U_{RRM}$	<b>600 ÷ 1100 V</b>
Turn-off time	$t_q$	<b>80; 100; 125 μs</b>
$U_{DRM}, U_{RRM}, V$	600	700
	800	900
	1000	1100
Voltage code	6	7
	8	9
	10	11
$T_{vj}, °C$	- 60 ÷ 140	

**MAXIMUM ALLOWABLE RATINGS**

Symbols and parameters		Units	TL271-320	Conditions
$I_{TAV}$	Mean on-state current	A	320 360	$T_c=104 °C$ , $T_c=100 °C$ 180° half-sine wave, 50 Hz
$I_{TRMS}$	RMS on-state current	A	502	$T_c=104 °C$
$I_{TSM}$	Surge on-state current	kA	9,0 10,0	$T_{vj}=140°C$ $T_{vj}=25°C$ tp=10 ms $U_R=0$
$I^2t$	Limiting load integral	kA <sup>2</sup> s	405 500	$T_{vj}=140°C$ $T_{vj}=25°C$
$U_{DRM}, U_{RRM}$	Repetitive peak off-state and reverse voltage	V	600÷1100	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz Gate open
$U_{DSM}, U_{RSM}$	Non-repetitive peak off-state and reverse voltage	V	660÷1210	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave tp=10 ms, Single pulse Gate open
$(di_T/dt)_{crit}$	Critical rate of rise of on-state current : non - repetitive repetitive	A/μs	250 125	$T_{vj}=140°C$ ; $U_D=0,67 U_{DRM}$ , Gate pulse : 10V, 5 μs, 1 μs rise time, 10 μs
$U_{RGM}$	Peak reverse gate voltage	V	5	$T_j \min \leq T_{vj} \leq T_{jM}$
$P_{RSM}$	Surge reverse power dissipation	kW	40	$T_{vj}=140°C$ ; tp = 10μs 180° half-sine wave
$T_{stg}$	Storage temperature	°C	-60÷80	
$T_{vj}$	Junction temperature	°C	-60÷140	

**CHARACTERISTICS**

$U_{TM}$	Peak on-state voltage	V	1,62	$T_{vj}=25°C$ , $I_{TM}=3,14 I_{TAV}$
$U_{T(TO)}$	Threshold voltage	V	0,9	$T_{vj}=140°C$
$R_T$	On-state slope resistance	mΩ	0,63	1,57 $I_{TAV} < I_T < 4,71 I_{TAV}$
$I_{DRM}$ $I_{RRM}$	Repetitive peak off-state and reverse current	mA	35 35	$T_{vj}=140°C$ , $U_D = U_{DRM}$ $U_R = U_{RRM}$

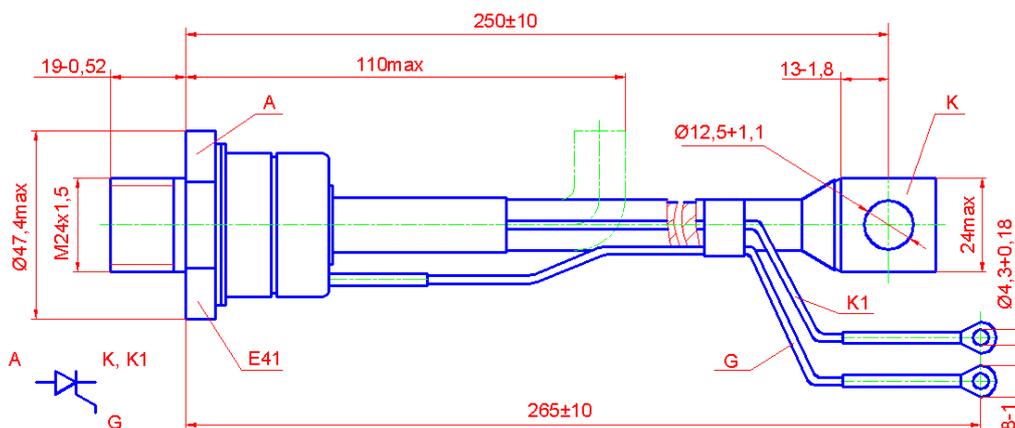
## CHARACTERISTICS

Symbols and parameters		Units	TL271-320	Conditions
$I_L$	Latching current	A	0,7	$T_{vj}=25^{\circ}\text{C}, U_D=12\text{V}$ Gate pulse : 10V, 5 $\Omega$ , 1 $\mu\text{s}$ rise time, 10 $\mu\text{s}$
$I_H$	Holding current	A	0,3	$T_{vj}=25^{\circ}\text{C}, U_D=12\text{V}$ , Gate open
$U_{GT}$	Gate trigger direct voltage	V	2,5 5,0	$T_{vj}=25^{\circ}\text{C}$ , $T_{vj}=-60^{\circ}\text{C}$ $U_D=12\text{V}$
$I_{GT}$	Gate trigger direct current	A	0,3 0,85	$T_{vj}=25^{\circ}\text{C}$ , $T_{vj}=-60^{\circ}\text{C}$
$U_{GD}$	Gate non-trigger direct voltage	V	0,4	$T_{vj}=140^{\circ}\text{C}$ , $U_D = 0,67 U_{DRM}$
$I_{GD}$	Gate non-trigger direct current	mA	6	Direct gate current
$t_{gd}$	Delay time	$\mu\text{s}$	1,6	$T_{vj}=25^{\circ}\text{C}, U_D=500\text{V}$ $I_{TM} = 320\text{ A}$
$t_{gt}$	Turn-on time	$\mu\text{s}$	3,2	Gate pulse : 10V, 5 $\Omega$ , 1 $\mu\text{s}$ rise time, 10 $\mu\text{s}$
$t_q$	Turn-off time	$\mu\text{s}$	80 $\div$ 125	$T_{vj}=140^{\circ}\text{C}$ , $I_{TM}=320\text{ A}$ $di_R/dt = 10\text{ A}/\mu\text{s}$ , $U_R=100\text{V}$ $U_D = 0,67 U_{DRM}$ $du_D/dt=50\text{ V}/\mu\text{s}$
$Q_{rr}$	Recovered charge	$\mu\text{C}$	600	$T_{vj}=140^{\circ}\text{C}$ , $I_{TM}=320\text{ A}$
$t_{rr}$	Reverse recovery time	$\mu\text{s}$	6	
$I_{rrm}$	Peak reverse recovery current	A	200	$di_R/dt = 10\text{ A}/\mu\text{s}$ , $U_R=100\text{V}$
$(du_D/dt)_{crit}$	Critical rate of rise of off-state voltage	V/ $\mu\text{s}$	500 1000	$T_{vj}=140^{\circ}\text{C}$ , $U_D = 0,67 U_{DRM}$ Gate open
$R_{thjc}$	Thermal resistance junction to case	$^{\circ}\text{C}/\text{W}$	0,08	Direct current

## ORDERING

	TL	271	320	11	7	0	
	1	2	3	4	5	6	

1. Avalanche thyristor
2. Design version
3. Mean on-state current, A
4. Voltage code (11=1100 V)
5. Critical rate of rise of off-state voltage ( $6 \geq 500\text{ V}/\mu\text{s}$ ,  $7 \geq 1000\text{ V}/\mu\text{s}$ )
6. Group of turn-off time ( $du_D/dt=50\text{ V}/\mu\text{s}$ ,  $X2 \leq 125\ \mu\text{s}$ ,  $4 \leq 100\ \mu\text{s}$ ,  $B3 \leq 80\ \mu\text{s}$ , 0- not limited)



Tightening torque : 40  $\div$  60 Nm  
Weight : 480 grams